

μC-Controlled Speech and Ringer Circuit

Description

The μC -controlled telephone circuit U4037B-N is a linear integrated circuit for use in telephone sets. It contains the speech circuit, tone-ringer interface, sidetone equiva-

lent and ear-protection rectifiers. The circuit is line powered and contains all components necessary for amplification of signals and adaptation to the line.

Features

- DC characteristic adjustable
- Receive gain adjustable
- Symmetrical input of microphone amplifier
- Anti-clipping in transmit direction
- Automatic line-loss compensation
- Symmetrical output of earpiece amplifier
- Built-in ear protection
- DTMF and MUTE input
- Adjustable sidetone suppression independent of sending and receiving amplification
- Power down
- Tone-ringer interface

- 2-bit D/A for volume control
- Supply voltages for all functional blocks of a subscriber set
- Operation possible from 8-mA line currents

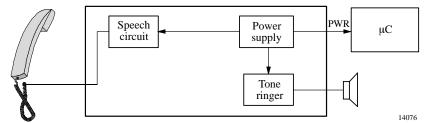
Benefits

- Complete system integration of analog signal processing on one chip
- Very few external components

Applications

Telephone sets

Block Diagram



Ordering Information

Туре	Package	Remarks
U4037B-NFL	SO24	
U4037B-NFLG3	SO24	Taped and reeled

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Pin Description

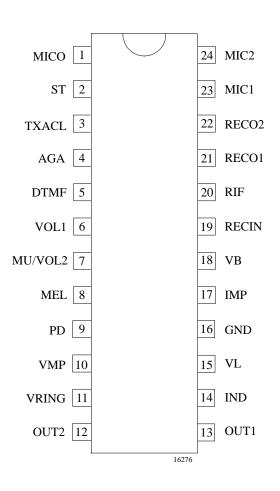


Figure 1. Pinning

Pin	Symbol	Function
1	MICO	Output of microphone preamplifier
2	ST	Sidetone reduction input input resistance is approx. 25 k Ω .
3	TXACL	Time constant of anti-clipping in transmit path
4	AGA	Automatic gain adjustment with line current, a resistor connected from this pin to GND sets the starting point maximum gain change: 6 dB.
5	DTMF	Input for DTMF signals

Pin	Symbol	Function				
6	VOL1	2-bit volume adjustment for tone				
		ringer				
7	MU/	1. 2-bit volume adjustment for tone				
	VOL2	ringer				
		2. Mute of microphone amplifier:				
		- Speech condition,				
		input MU/VOL2 low				
		DTMF condition input MU/VOL2 high				
		DTMF signal at Pin 5 is fed to				
		the line. A part of the DTMF-				
		signal is passed to the receiving				
		amplifier as a confidence signal				
		during dialing.				
8	MEL	Input for melody				
9	PD	Active high input for reducing the				
		current consumption of the circuit,				
		simultaneously V _L is shorted by an				
10	10.00	internal switch				
10	VMP	Regulated supply voltage 3.4 V for				
		peripheral circuits (esp. microprocessors), minimum output current:				
		2 mA (ringing) 4 mA (speech mode)				
11	VRING	Input for ringersupply voltage				
12	OUT2	Differential output for tone ringer				
13	OUT1	Differential output for tone ringer				
14	IND	The internal equivalent inductance				
1.	11,12	of the circuit is proportional to the				
		value of the capacitor at this pin, a				
		resistor connected to ground may be				
		used to reduce the DC line voltage				
15	VL	Line voltage				
16	GND	Reference point for DC- and AC-				
		output signals				
17	IMP	Impedance adjustment				
18	VB	Unregulated supply voltage for				
		peripheral circuits (voice switch),				
4.0	DEC.	limited to typically 7 V				
19	RECIN	Receiver input				
20	RIF	Pin for adjustment of frequency				
21	DECO1	response and gain of receiver				
21	RECO1	Output of receiving amplifier				
22	RECO2	Inverting output of receiving ampl.				
23	MIC1	Inverting input of microphone ampl.				
24	MIC2	Non-inverting input of microphone				
		amplifier				



Detailed Block Diagram with External Components

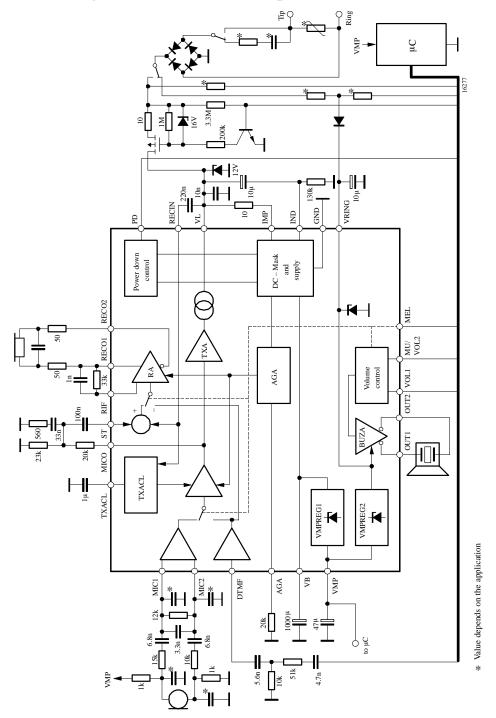


Figure 2. Application circuit

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Absolute Maximum Ratings

Parameters	Symbol	Value	Unit
Line current	I_{L}	140	mA
DC line voltage	$V_{\rm L}$	12	V
Maximum input current	I _{RING}	15	mA
Junction temperature	Ti	125	°C
Ambient temperature	T _{amb}	-25 to +75	°C
Storage temperature	T _{stg}	−55 to +150	°C
Total power dissipation, $T_{amb} = 60^{\circ}C$	P _{tot}	520	W

Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient SO24	R _{thJA}	75	K/W

Electrical Characteristics

 $f=1~kHz, 0~dBm=775~mV_{rms}, I_{MP}=2~mA, T_{amb}=25^{\circ}C, Z_{ear}=68~nF+100~\Omega, Z_{M}=68~nF, unless~otherwise~specified~approx 100~mJ/m = 100$

Parameters	Test Conditions / Pin	Symbol	Min.	Тур.	Max.	Unit
DC characteristics						
DC voltage drop over circuit	$\begin{split} I_L &= 2 \text{ mA} \\ I_L &= 14 \text{ mA} \\ I_L &= 60 \text{ mA} \end{split}$	$V_{\rm L}$	4.6	2.4 5.0 7.5	5.4	V
	$I_L = 100 \text{ mA}$		8.8	9.4	10.0	
Transmission amplifier, $I_L = 14 \text{ m}$	A , $V_{MIC} = 2$ mV, unless oth	erwise spe	cified			
Transmitting amplification		G _T	47	48	49	dB
Frequency response	$I_L \ge 14 \text{ mA},$ f = 300 to 3400 Hz	ΔG_{T}			± 0.5	dB
Gain change with current	$I_L = 14 \text{ to } 100 \text{ mA}$	ΔG_{T}			± 0.5	dB
Gain deviation	$T_{amb} = -10 \text{ to } +60 ^{\circ}\text{C}$	ΔG_{T}			±0.5	dB
CMRR of microphone amplifier		CMRR	60	80		dB
Input resistance of MIC amplifier		Ri		50		kΩ
Distortion at line	$I_L > 14 \text{ mA}$ $V_L = 700 \text{ mV}_{rms}$	d _t			2	%
Maximum output voltage	$\begin{split} I_L > 19 \text{ mA, d} < 5\% \\ V_{mic} = 10 \text{ mV} \\ CTXA = 1 \mu\text{F} \end{split}$	V _{Lmax}	1.8	3	4.2	dBm
Noise at line psophometrically weighted	$I_L > 14 \text{ mA}$ $G_T = 48 \text{ dB}$	no		-80	-72	dBmp
Anti-clipping attack time release time	CTXA = 1 μ F each 3 dB overdrive			0.5 9		ms
Line-loss compensation	$\begin{split} I_L &= 100 \text{ mA}, \\ RAGA &= 20 \text{ k}\Omega \end{split}$	ΔG_{TI}	-6.4	-5.8	-5.2	dB
Mute suppression	$I_L \ge 14 \text{ mA}$	G _{TM}	60	80		dB



Electrical Characteristics (continued)

Parameters	Test Conditions / Pin	Symbol	Min.	Тур.	Max.	Unit
Receiving amplifier, I_L = 14 mA, unless otherwise specified, V_{GEN} = 300 mV						
Receiving amplification		G_R			12	dB
Adjustment range		G_R	-8		12	dB
Amplification of DTMF signal from DTMF IN to RECO 1, 2	$I_{L} \ge 14 \text{ mA},$ $V_{DTMF} = 8 \text{ mV}$	G_{RM}	14		20	dB
Frequency response	I _L > 14 mA, f = 300 to 3400 Hz	ΔG_{RF}			± 0.5	dB
Gain change with current	I _L = 14 to 100 mA	ΔG_{R}			± 0.5	dB
Gain deviation	$T_{amb} = -10 \text{ to } +60^{\circ}\text{C}$	ΔG_R			± 0.5	dB
Ear protection differential	$\begin{array}{c} I_{L} \geq 14 \text{ mA} \\ V_{GEN} = 11 \text{ V}_{rms} \end{array}$	EP			2.2	V _{rms}
MUTE suppression	$I_L \ge 14 \text{ mA}$	ΔG_R	60			dB
Output voltage d ≤ 2% differential			0.775			V _{rms}
Output voltage d ≤ 5% differential	$\begin{split} I_L &= 14 \text{ mA} \\ Z_{ear} &= 68 \text{ nF} + 100 \Omega \\ RDC &= infinite \end{split}$		1.2			V _{rms}
Receiving noise psophometrically weighted	$Z_{\text{ear}} = 68 \text{ nF} + 100 \Omega$ $I_{\text{L}} \ge 14 \text{ mA}$	ni			-64	dBmp
Output resistance	each output against GND	Ro			40	Ω
Line-loss compensation	RAGA = $20 \text{ k}\Omega$, $I_L = 100 \text{ mA}$	ΔG_{RI}	-7.0	-6.0	-5.0	dB
Gain at low operating current	$\begin{split} I_L = 8 \text{ mA}, I_{MP} = 1 \text{ mA} \\ I_M = 300 \mu\text{A} \\ V_{GEN} = 100 \text{ mV} \\ RDC = 68 k\Omega \end{split}$	G_R	10.5	12	13.5	dB
DTMF-amplifier test condit	ions: IMP = 2 mA					
DTMF amplification	$\begin{split} I_L &= 15 \text{ mA}, \\ VDTMF &= 8 \text{ mV} \\ Mute \text{ active} \end{split}$	G_{D}	40.7	41.7	42.7	dB
Gain deviaton	$I_L = 15 \text{ mA}$ $T_{amb} = -10 \text{ to } +60 ^{\circ}\text{C}$	G_D			± 0.5	dB
Input resistance	$RGT = 15 k\Omega$	Ri	15	20	25	kΩ
Distortion of DTMF signal	$I_L \ge 15 \text{ mA},$ $V_L = 0 \text{ dBm}$	d_{D}			2	%
Gain deviation with current	I _L = 15 to 100 mA	ΔGD			± 0.5	dB
Supply voltages, $V_{mic} = 10 \text{ mV}$, T_{am}	$b = -10 \text{ to} + 60^{\circ}\text{C}$					
V_{MP}	$\begin{split} I_L &= 8 \text{ mA}, \\ RDC &= 130 \text{ k}\Omega \\ I_{MP} &= 1 \text{ mA} \end{split}$	V _{MP}	3.1	3.4	3.6	V
Ringing part, $I_{VMP} = 1 \text{ mA}$	T		T	1	1	ı
Maximum output voltage	$V_{RING} = 20 \text{ V}$	V _{out}		25		V _{pp}
Input impedance in speech mode	$ \begin{aligned} f &= 300 \text{ Hz to } 3400 \text{ Hz} \\ I_L &> 15 \text{ mA,} \\ V_{TIP/RING} &= 1.5 \text{ V}_{rms} \end{aligned} $	R _i	50			kΩ

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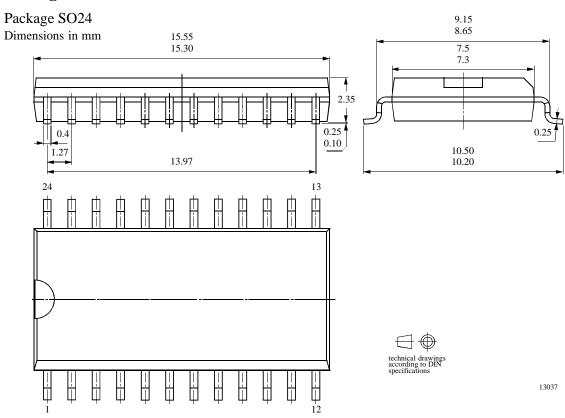
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Electrical Characteristics (continued)

Parameters	Test Conditions / Pin	Symbol	Min.	Тур.	Max.	Unit
	$f = 25 \text{ Hz}, C_{BUZ} = 50 \text{ nF}$					
Ringing part:	$V_{TIP/RING} = 63 V_{rms}$	V _{out}	28			V _{pp}
Ringer output voltage	$V_{TIP/RING} = 45 V_{rms}$	V _{out}		18		V_{pp}
	$V_{TIP/RING} = 25 V_{rms}$	V _{out}	7			V_{pp}
		11		0		
Volume adjustment steps		10		-6		dB
voidine adjustment steps		01		-12		
		00		-24		
Zener diode voltage	$I_{RING} = 25 \text{ mA}$	V _{RINGmax}		28.5		V
PD Input						
PD input current	PD active, $I_L > 14 \text{ mA}$ $V_{PD} = V_{MP}$	Ipd		9		uA
Input voltage	PD = active PD = inactive	$egin{array}{c} V_{ m pd} \ V_{ m pd} \end{array}$	2		0.3	V
Voltage drop at V _L	PD = active, $I_L = 14 \text{ mA}$ $I_L = 100 \text{ mA}$,	$egin{array}{c} V_{ m L} \ V_{ m L} \end{array}$		1.5 1.9		V
Internal current comsumption at V _B	$V_B = 3.5 \text{ V},$ PD = active, $I_L = 0 \text{ mA}$	I _B		300		μΑ

Package Information



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Ozone Depleting Substances Policy Statement

It is the policy of Atmel Germany GmbH to

- 1. Meet all present and future national and international statutory requirements.
- Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Atmel Germany GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Atmel Germany GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

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Data sheets can also be retrieved from the Internet: http://www.atmel-wm.com

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